We claim:

1	1.	A semiconductor optical device comprising:
2		a transverse Bragg resonance waveguide comprised in turn of a
3	waveg	guiding channel, and on at least two opposing sides of the channel two
4	periodic index media; and	
5		means for providing gain in the periodic index media.
1	2.	The semiconductor optical device of claim 1 where the device is included
2	within a laser.	
1	3.	The semiconductor optical device of claim 1 where the device is included
2		an amplifier.
1	4.	The semiconductor optical device of claim 1 where the device is included
2	within	an oscillator.
1	5.	The semiconductor optical device of claim 1 where the waveguiding
2	channel is planar and is sandwiched on two opposing sides by the periodic index	
3	media.	
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- 1 6. The semiconductor optical device of claim 1 where the waveguiding
- 2 channel is cylindrical and is surrounded by the periodic index media.
- 1 7. The semiconductor optical device of claim 1 where the means for
- 2 providing gain in the periodic index media is electrical.
- 1 8. The semiconductor optical device of claim 1 where the means for
- 2 providing gain in the periodic index media is optical.
- 1 9. The semiconductor optical device of claim 1 where the periodic index
- 2 media comprises a periodic lattice of regions having an index of refraction distinct
- 3 from the channel.
- 1 10. The semiconductor optical device of claim 9 where the periodic lattice
- 2 comprises an array of transverse holes defined in a planar semiconductor
- 3 substrate in which the channel is also defined.
- 1 . 11. The semiconductor optical device of claim 9 where the periodic lattice
- 2 comprises an array of longitudinal holes defined in a cylindrical semiconductor
- 3 fiber in which the channel is also longitudinally defined.
- 1 12. A method of operating a semiconductor optical device comprising:

- 2 propagating a light wave within a transverse Bragg resonance waveguide
- 3 comprised of a waveguiding channel, and on at least two opposing sides of the
- 4 channel two periodic index media; and
- 5 providing gain in the periodic index media while propagating the light
- 6 wave.
- 1 13. The method of claim 12 where propagating a light wave is performed
- 2 within a laser.
- 1 14. The method of claim 12 where propagating a light wave is performed
- 2 within an amplifier.
- 1 15. The method of claim 12 where propagating a light wave is performed
- 2 within an oscillator.
- 1 16. A method of providing an active transverse Bragg resonance waveguide
- 2 comprising fabricating a planar waveguiding channel and sandwiching the planar
- 3 waveguiding channel on two opposing sides by a periodic index media, and
- 4 providing gain to the periodic index media.
- 1 17. A method of providing an active transverse Bragg resonance waveguide
- 2 comprising fabricating a cylindrical waveguiding channel and surrounding the

- 3 cylindrical waveguiding channel by a periodic index media, and providing gain to
- 4 the periodic index media.
- 1 18. The method of claim 12 where providing gain in the periodic index media
- 2 comprises electrically pumping the periodic index media.
- 1 19. The method of claim 12 where providing gain in the periodic index media
- 2 comprises optically pumping the periodic index media.
- 1 20. The method of claim 12 where propagating a light wave comprises
- 2 propagating a light wave at a detuned frequency given by $k_0 = (1 + v) \pi / b$ where
- k_0 is the modal wave number of the propagated light, v is the frequency, and b is
- 4 the transverse periodicity of the periodic index media.
- 1 21. The method of claim 12 where the semiconductor optical device is
- 2 operated in a mode which has a gain enhancement, η, due to an increase of a
- 3 gain constant, β_l , of the propagating wave over the gain constant of a bulk
- 4 dielectric and a substantial electric field content outside the channel leading to a
- 5 larger modal cross-sectional area, and higher output power.